# VS-MB High Voltage Series

**Vishay Semiconductors** 

## **Single Phase Bridge** (Power Modules), 25 A/35 A



www.vishay.com

D-34

| PRIMARY CHARACTERISTICS |                     |  |  |
|-------------------------|---------------------|--|--|
| lo                      | 25 A to 35 A        |  |  |
| V <sub>RRM</sub>        | 1400 V to 1600 V    |  |  |
| Package                 | D-34                |  |  |
| Circuit configuration   | Single phase bridge |  |  |

#### **FEATURES**

• Universal, 3 way terminals: push-on, wrap around or solder



COMPLIANT

- · High thermal conductivity package, electrically insulated case
- Center hole fixing
- Excellent power/volume ratio
- Nickel plated terminals solderable using lead (Pb)-free solder; solder alloy Sn/Ag/Cu (SAC305); solder temperature 260 °C to 275 °C
- UL E300359 approved
- Designed and qualified for industrial and consumer level
- Material categorization: for definitions of compliance please see www.vishay.com/doc?99912

#### DESCRIPTION

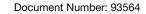
A range of extremely compact, encapsulated single phase bridge rectifiers offering efficient and reliable operation. They are intended for use in general purpose and instrumentation applications.

| MAJOR RATINGS AND CHARACTERISTICS |                 |                 |                 |                  |  |
|-----------------------------------|-----------------|-----------------|-----------------|------------------|--|
| SYMBOL                            | CHARACTERISTICS | VALUES<br>26MBA | VALUES<br>36MBA | UNITS            |  |
|                                   |                 | 25              | 35              | A                |  |
| IO                                | T <sub>C</sub>  | 70              | 55              | °C               |  |
| 1                                 | 50 Hz           | 400             | 475             | ٨                |  |
| IFSM                              | 60 Hz           | 420             | 500             | A                |  |
| l <sup>2</sup> t                  | 50 Hz           | 790             | 1130            | A <sup>2</sup> s |  |
| 141                               | 60 Hz           | 725             | 1030            | A-S              |  |
| V <sub>RRM</sub>                  | Range           | 1400 to 1600    |                 | V                |  |
| TJ                                |                 | -55 to 150      |                 | °C               |  |

#### **ELECTRICAL SPECIFICATIONS**

| VOLTAGE RATINGS |  |      |  |   |  |
|-----------------|--|------|--|---|--|
| TYPE<br>NUMBER  | VOLTAGE<br>CODE<br>VRRM, MAXIMUM REPETITIVE<br>PEAK REVERSE VOLTAGE<br>V |      | V <sub>RSM</sub> , MAXIMUM NON-REPETITIVE<br>PEAK REVERSE VOLTAGE<br>V | I <sub>RRM</sub> MAXIMUM<br>AT T <sub>J</sub> MAXIMUM<br>mA |  |
| 26MBA           | 140  | 1400 | 1500   | 2   |  |
| 36MBA           | 160  | 1600 | 1700   | ۲   |  |

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| <b>FORWARD C</b> | ONDUCTION |
|------------------|-----------|
|------------------|-----------|

| PARAMETER  | SYMBOL              | TEST CONDITIONS   |                                     | VALUES<br>26MBA                         | VALUES<br>36MBA | UNITS |                  |
|--|---------------------|---|-------------------------------------|---|-----------------|-------|------------------|
|  | Io                  | Resistive or inductive load   |                                     | 25                                      | 35              | А     |                  |
| Maximum DC output current<br>at case temperature |                     | Capacitive loa  | ad                                  |   | 20              | 28    | А                |
| a case temperature                               |                     |   |                                     |   | 65              | 60    | °C               |
|  |                     | t = 10 ms   | No voltage                          | Initial                                 | 400             | 475   | A                |
| Maximum peak, one cycle                          |                     | t = 8.3 ms  | reapplied                           |   | 420             | 500   |                  |
| non-repetitive forward current                   | I <sub>FSM</sub>    | t = 10 ms   | 100 % V <sub>BBM</sub>              |   | 335             | 400   |                  |
|  |                     | t = 8.3 ms  | reapplied                           |   | 350             | 420   |                  |
| Maximum I <sup>2</sup> t for fusing              | l <sup>2</sup> t    | t = 10 ms   | No voltage                          | T <sub>J</sub> = T <sub>J</sub> maximum | 790             | 1130  | A <sup>2</sup> s |
|  |                     | t = 8.3 ms  | reapplied                           |   | 725             | 1030  |                  |
|  |                     | t = 10 ms   | 100 % V <sub>RRM</sub><br>reapplied |   | 560             | 800   |                  |
|  |                     | t = 8.3 ms  |                                     |   | 512             | 730   |                  |
| Maximum I <sup>2</sup> $\sqrt{t}$ for fusing     | l²√t                | $ \begin{array}{l} l^2 t \text{ for time } t_x = l^2 \sqrt{t} \; x \; \sqrt{t_x}; \\ 0.1 \leq t_x \leq 10 \; \text{ms}, \; V_{\text{RRM}} = 0 \; \text{V} \end{array} $ |                                     | 5.6                                     | 11.3            | kA²√s |                  |
| Low level of threshold voltage                   | V <sub>F(TO)1</sub> | (16.7 % x π x I <sub>F(AV)</sub> < I < π x I <sub>F(AV)</sub> ),<br>T <sub>J</sub> maximum  |                                     | 0.70                                    | 0.74            | V     |                  |
| High level of threshold voltage                  | V <sub>F(TO)2</sub> | $(I > \pi x I_{F(AV)}), T_J$ maximum  |                                     | 0.75                                    | 0.79            |       |                  |
| Low level forward slope resistance               | r <sub>t1</sub>     | (16.7 % x π x I <sub>F(AV)</sub> < I < π x I <sub>F(AV)</sub> ),<br>T <sub>J</sub> maximum  |                                     | 7.0                                     | 5.5             | mΩ    |                  |
| High level forward slope resistance              | r <sub>t2</sub>     | $(I > \pi \times I_{F(AV)}), T_J$ maximum   |                                     | 6.4                                     | 5.2             |       |                  |
| Maximum forward voltage drop                     | $V_{FM}$            | $\begin{array}{l} T_{J}{=}25\;{}^{\circ}\text{C},t_{p}{=}400\mu\text{s},I_{FM}{=}40A_{pk}(26\text{MB}),\\ I_{FM}{=}55\;A_{pk}(36\text{MB}) \end{array}$                 |                                     | 1.25                                    | 1.3             | V     |                  |
| Maximum DC reverse current per diode             | I <sub>RRM</sub>    | T <sub>J</sub> = 25 °C, at V <sub>RRM</sub>   |                                     | 10                                      | 10              | μA    |                  |
| RMS isolation voltage base plate                 | VISOL               | f = 50 Hz, t = 1 s  |                                     | 2700                                    | 2700            | V     |                  |

| THERMAL AND MECHANICAL SPECIFICATIONS                   |                                   |  |                  |                  |        |
|---|-----------------------------------|--|------------------|------------------|--------|
| PARAMETER   | SYMBOL                            | TEST CONDITIONS                            | VALUES<br>26MB-A | VALUES<br>36MB-A | UNITS  |
| Junction and storage temperature range                  | T <sub>J</sub> , T <sub>Stg</sub> |  | -55 to           | o 150            | °C     |
| Maximum thermal resistance, junction to case per bridge | R <sub>thJC</sub>                 |  | 1.7              | 1.35             | K/W    |
| Maximum thermal resistance, case to heatsink            | R <sub>thCS</sub>                 | Mounting surface, smooth, flat and greased | 0.2              |                  | r\/ vv |
| Mounting torque ± 10 %                                  |                                   | Bridge to heatsink                         | 2                | .0               | Nm     |
| Approximate weight                                      |                                   |  | 2                | 0                | g      |

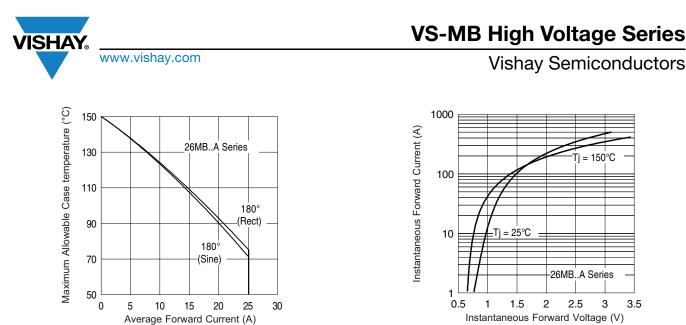


Fig. 1 - Current Ratings Characteristics

Fig. 2 - Forward Voltage Drop Characteristics

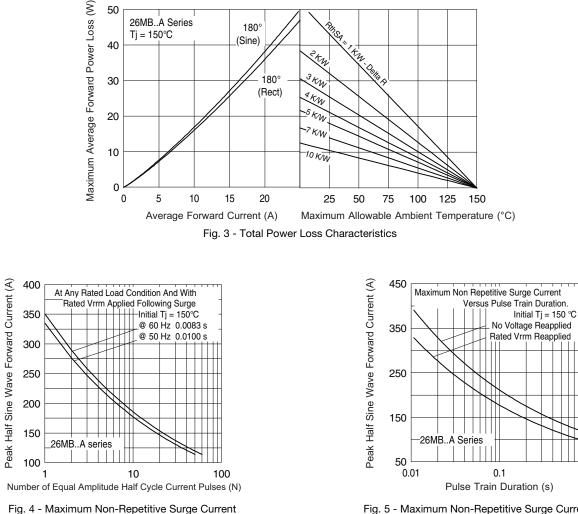


Fig. 5 - Maximum Non-Repetitive Surge Current

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## **VS-MB High Voltage Series**

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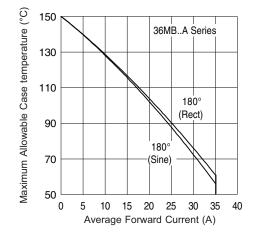


Fig. 6 - Current Ratings Characteristics

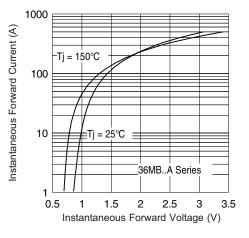


Fig. 7 - Forward Voltage Drop Characteristics

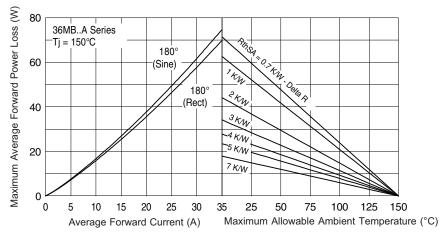
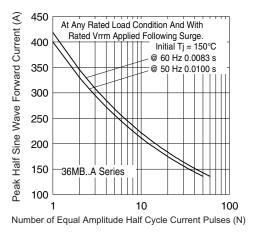


Fig. 8 - Total Power Loss Characteristics





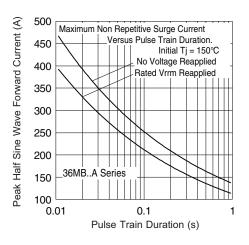


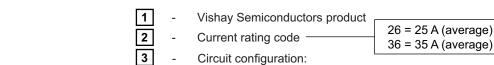
Fig. 10 - Maximum Non-Repetitive Surge Current

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36

2

VS-

1

4

MB = Single phase european coding

160

4

Α

5

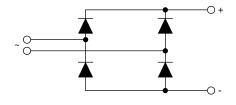
- Voltage code x 10 = V<sub>RRM</sub>
  - Diode bridge rectifier:

MB

(3)

A = 26 MB, 36 MB series

### CIRCUIT CONFIGURATION



| LINKS TO RELATED DOCUMENTS |                          |  |  |
|----------------------------|--------------------------|--|--|
| Dimensions                 | www.vishay.com/doc?95326 |  |  |

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**ORDERING INFORMATION TABLE** 

**Device code** 

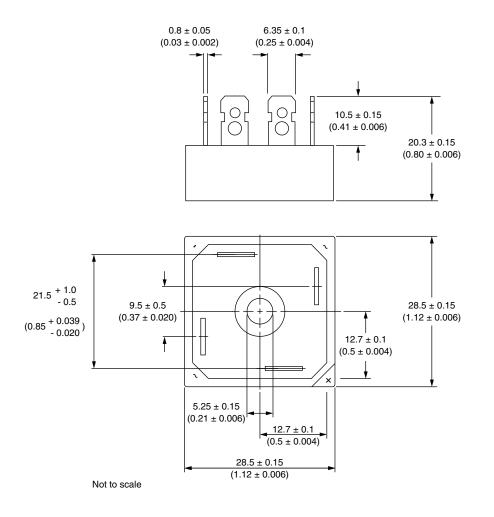


## **Outline Dimensions**

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**D-34** 

### **DIMENSIONS** in millimeters (inches)



Suggested plugging force: 200 N max; axially applied to fast-on terminals



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